В

GND

- Operating Range: 2-V to 5.5-V V_{CC}
- EPIC™ (Enhanced-Performance Implanted **CMOS) Process**
- **Packaged in Plastic Small-Outline Transistor Package**

description

The SN74AHC1G86 is a single 2-input exclusive-OR gate. The device performs the Boolean function $Y = A \oplus B$ or $Y = \overline{AB} + A\overline{B}$ in positive logic.

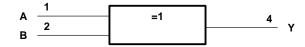
A common application is as a true/complement element. If one of the inputs is low, the other input is reproduced in true form at the output. If one of the inputs is high, the signal on the other input is reproduced inverted at the output.

The SN74AHC1G86 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE

INP	UTS	OUTPUT
Α	В	Υ
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



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A = B).

exclusive-OR logic

An exclusive-OR gate has many applications, some of which can be represented better by alternative logic symbols.



These are five equivalent exclusive-OR symbols valid for an SN74AHC1G86 gate in positive logic; negation may be shown at any two ports.

LOGIC-IDENTITY ELEMENT EVEN-PARITY ELEMENT ODD-PARITY ELEMENT Zk Zk+1 The output is active (low) if all inputs stand at the same logic level (i.e., only 1 of inputs (i.e

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

the 2) are active.

active.

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1)	0.5 V to 7 V
Output voltage range, V _O (see Note 1)	\dots -0.5 V to V _{CC} + 0.5 V
Input clamp current, I _{IK} (V _I < 0)	–20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±25 mA
Continuous current through V _{CC} or GND	±50 mA
Maximum power dissipation at $T_A = 55^{\circ}C$ (in still air) (see Note 2)	0.2 W
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



^{2.} The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 25 millimeters.

PRODUCT PREVIEW

recommended operating conditions (see Note 3)

			MIN	MAX	UNIT
VCC	Supply voltage		2	5.5	V
		V _{CC} = 2 V	1.5		
V_{IH}	High-level input voltage	V _{CC} = 3 V	2.1		V
		$V_{CC} = 5.5 \text{ V}$	3.85		
		V _{CC} = 2 V		0.5	
V_{IL}	Low-level input voltage	V _{CC} = 3 V		0.9	V
		V _{CC} = 5.5 V		1.65	
٧ _I	Input voltage		0	5.5	V
٧o	Output voltage		0	Vcc	V
	V _{CC} = 2 V			-50	μΑ
lOH	High-level output current $ V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V} $ $ V_{CC} = 5 \text{ V} \pm 0.5 \text{ V} $		-4	mA	
			-8	IIIA	
		V _{CC} = 2 V		50	μΑ
lOL	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	mA
	$V_{CC} = 5 V \pm 0.5 V$			8	IIIA
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100	ns/V
	Input transition rise or fall rate $\frac{CC}{V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}}$			20	115/V
T _A	Operating free-air temperature		-40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	T _A = 25°C			MINI	MAY	UNIT
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	UNIT
		2 V	1.9	2		1.9		
	I _{OH} = -50 μA	3 V	2.9	3		2.9		
VOH		4.5 V	4.4	4.5		4.4		V
	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		
	I _{OH} = -8 mA	4.5 V	3.94			3.8		
					0.1		0.1	
	I _{OL} = 50 μA	3 V			0.1		0.1	
V _{OL}		4.5 V			0.1		0.1	V
	I _{OL} = 4 mA	3 V			0.36		0.44	
	I _{OL} = 8 mA	4.5 V			0.36		0.44	
I _I A or B inputs	$V_I = V_{CC}$ or GND	5.5 V			± 0.1		± 1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			2		20	μΑ
Ci	$V_I = V_{CC}$ or GND	5 V		4	10		10	pF

SCLS323A - MARCH 1996 - REVISED MAY 1996

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	го оитрит		T _A = 25°C			MAX	UNIT		
FARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN MAX	IVIAA	UNIT		
^t PLH	A or B	Y	Y C _L = 15 pF	A or B Y C _L = 15 pF	A or P V C: - 15 pE		7	11	1	13	no
^t PHL	AUIB				7	11	1	13	ns		
^t PLH	A or B	V	C: _ 50 pE		9.5	14.5	1	16.5	no		
^t PHL		ľ	I	Ĭ	T T	C _L = 50 pF		9.5	14.5	1	16.5

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	AMETER FROM (INPUT)	TO OUTPUT CAPACITANCE	T _A = 25°C			MIN	MAX	UNIT		
			CAPACITANCE	MIN	TYP	MAX	IVIIIN	WAX	UNII	
t _{PLH}	A or B	Y C	O: 45 mF		4.8	6.8	1	8		
t _{PHL}			ľ	<u> </u>	'	C _L = 15 pF		4.8	6.8	1
^t PLH	A or B	V	C 50 pF		6.3	8.8	1	10	20	
tPHL	AUID	ī	C _L = 50 pF		6.3	8.8	1	10	ns	

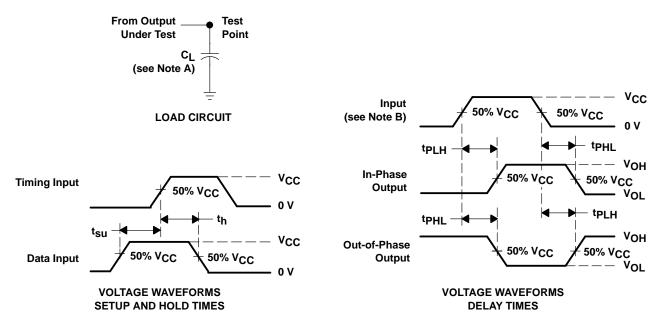
operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER		TEST CO	NDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	18	pF



PRODUCT PREVIEW

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_{O} = 50 \Omega$, $t_{f} = 3 \text{ ns}$, $t_{f} = 3 \text{ ns}$.
- C. The output is measured with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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